

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------|------------------|---------|------------------|
| L1 | 2 | "20020135640" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/02/14 11:46 |
| L2 | 2 | "5861902".pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/02/14 11:47 |
| S1 | 2 | "20050231557" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/10/31 15:11 |
| S2 | 7 | ("2002046266" "0405204" "0456872").pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:36 |
| S3 | 27 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:07 |
| S4 | 288 | "347"/\$3 and micro\$fluid\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 13:35 |
| S5 | 176 | "347"/\$3 and micro\$fluid\$2 and silicon | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 13:36 |
| S6 | 55 | "347"/\$3 and micro\$fluid\$2 and silicon and (di\$electric\$2 or bi\$electric\$2) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 13:43 |

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| S7 | 55 | "347"/\$3 and micro\$fluid\$2 and silicon and (di\$electric\$2 or bi\$electric\$2) and (angstrom\$1 or A) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 13:41 |
| S8 | 103 | "347"/\$3 and micro\$fluid\$2 and silicon same (path\$1 or pathway\$1 or channel\$1 or trench\$2 or opening\$1) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 13:49 |
| S9 | 58 | "347"/\$3 and micro\$fluid\$2 and silicon same (path\$1 or pathway\$1 or channel\$1 or trench\$2 or opening\$1) and ion | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 13:50 |
| S10 | 24 | "347"/\$3 and micro\$fluid\$2 and silicon same (path\$1 or pathway\$1 or channel\$1 or trench\$2 or opening\$1) and ion and di\$electric\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 13:51 |
| S11 | 3 | "347"/\$3 and micro\$fluid\$2 and silicon same (path\$1 or pathway\$1 or channel\$1 or trench\$2 or opening\$1) and ion and di\$electric\$2 and (pitting or pitted) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 15:06 |
| S12 | 3 | "347"/\$3 and micro\$fluid\$2 and silicon same (path\$1 or pathway\$1 or channel\$1 or trench\$2 or opening\$1) and ion and di\$electric\$2 and angstrom\$1 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 15:02 |
| S13 | 24 | "347"/\$3 and micro\$fluid\$2 and silicon same (path\$1 or pathway\$1 or channel\$1 or trench\$2 or opening\$1) and ion and di\$electric\$2 and A | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 15:25 |
| S14 | 0 | ("6179401" "6637866" "5850242" "20040113988").pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 15:08 |

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| S15 | 8 | ("6179401" "6637866" "5850242" "20040113988").pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/30 15:08 |
| S16 | 11417 | (Krawczyk.in. or McNees.in. or Mrvos.in. or Sullivan.in.) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 15:17 |
| S17 | 110 | (Krawczyk.in. or McNees.in. or Mrvos.in. or Sullivan.in.) and Lexmark | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 15:17 |
| S18 | 9 | (Krawczyk.in. or McNees.in. or Mrvos.in. or Sullivan.in.) and Lexmark and micro\$fluid\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/30 15:17 |
| S20 | 24 | "347"/\$3 and micro\$fluid\$2 and silicon same (path\$1 or pathway\$1 or channel\$1 or trench\$2 or opening\$1) and ion and di\$electric\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/31 08:23 |
| S21 | 0 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and micro\$fluid\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 07:52 |
| S22 | 47 | "347"/\$3 and di\$electric\$2 with angstrom\$1 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/31 08:02 |
| S23 | 3 | "347"/\$3 and di\$electric\$2 with angstrom\$1 and micro\$fluid\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/31 08:16 |

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| S24 | 33 | "347"/\$3 and micro\$fluid\$2 and silicon same (path\$1 or pathway\$1 or channel\$1 or trench\$2 or opening\$1) and (ion or etch\$3) and di\$electric\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/31 08:25 |
| S25 | 0 | TW0405204B | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:36 |
| S26 | 394544 | TW 0405204B | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:36 |
| S27 | 0 | TW and 0405204B | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:37 |
| S28 | 0 | TW and "0405204" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:37 |
| S29 | 0 | TW and "00405204" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:37 |
| S30 | 46 | CHEN.in. and WU.in. and LUR.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:40 |
| S31 | 0 | CHEN.in. and WU.in. and LUR.in. and micro\$fluid\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:40 |

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| S32 | 27 | CHEN.in. and WU.in. and LUR.in. and silicon | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:40 |
| S33 | 10 | CHEN.in. and WU.in. and LUR.in. and silicon and di\$electric\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:41 |
| S34 | 10 | CHEN.in. and WU.in. and LUR.in. and silicon and di\$electric\$2 and etch\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:49 |
| S35 | 1554385 | CHEN.in. and WU.in. and LUR.in. and silicon and di\$electric\$2 and etch\$3 adn oxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:49 |
| S36 | 8 | CHEN.in. and WU.in. and LUR.in. and silicon and di\$electric\$2 and etch\$3 and oxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 09:42 |
| S37 | 0 | CHEN.in. and WU.in. and LUR.in. and silicon and di\$electric\$2 and etch\$3 and oxide and root same mean same square | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:51 |
| S38 | 123667 | CHEN.in. and WU.in. and LUR.in. and silicon and di\$electric\$2 and etch\$3 and oxide (pit or pitting) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:52 |
| S39 | 0 | CHEN.in. and WU.in. and LUR.in. and silicon and di\$electric\$2 and etch\$3 and oxide and (pit or pitting) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 08:52 |

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| S40 | 21 | CHEN.in. and WU.in. and LUR.in. and silicon and etch\$3 and oxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 09:48 |
| S41 | 3 | CHEN.in. and WU.in. and LUR.in. and silicon and etch\$3 and oxide and (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:02 |
| S42 | 3 | CHEN.in. and WU.in. and LUR.in. and silicon and etch\$3 and (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:02 |
| S43 | 1775 | micro\$fluid\$2 and silicon and etch\$3 and (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:03 |
| S44 | 7 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:08 |
| S45 | 7 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and (angstrom\$1 or nanometer\$1 or nm) and silicon | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:08 |
| S46 | 7 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and (angstrom\$1 or nanometer\$1 or nm) and silicon and (etch\$3) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:10 |

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| S47 | 7 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and (angstrom\$1 or nanometer\$1 or nm) and silicon and (etch\$3) and oxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:10 |
| S48 | 7 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and (angstrom\$1 or nanometer\$1 or nm) and silicon and (etch\$3) and oxide and (thick\$4 or depth) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:15 |
| S49 | 6 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate and (etch\$3) and oxide and (thick\$4 or depth) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:20 |
| S50 | 5 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate same (etch\$3) and oxide and (thick\$4 or depth) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:26 |
| S51 | 7 | ("3958255" "5087591" "5320932" "5350491" "5350492" "5362356" "6204182" "6207491" "6284606" "6294474" "6402301" "6595627" "6620732" "20010077163").pn. and (angstrom\$1 or nanometer\$1 or nm) and silicon with (etch\$3) and oxide and (thick\$4 or depth) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 12:16 |
| S52 | 98 | (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate with (etch\$3) and oxide and (thick\$4 or depth) and root near1 mean near1 square | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:39 |

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| S53 | 26 | (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate with (etch\$3) and oxide and (thick\$4 or depth) same root near1 mean near1 square | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:38 |
| S54 | 1 | (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate with (etch\$3) and oxide and (thick\$4 or depth) same root near1 mean near1 square and micro\$fluid\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:39 |
| S55 | 1 | (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate with (etch\$3) and oxide and (thick\$4 or depth) and root near1 mean near1 square and microfluid | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:39 |
| S56 | 4 | (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate with (etch\$3) and oxide and (thick\$4 or depth) and root near1 mean near1 square and micro\$fluid\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:40 |
| S57 | 254 | (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate with (etch\$3) and oxide and (thick\$4 or depth) and micro\$fluid\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:42 |
| S58 | 44 | (angstrom\$1 or nanometer\$1 or nm) and silicon near3 substrate with (etch\$3) and oxide and (thick\$4 or depth) and micro\$fluid\$2 and ink\$jet\$4 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 10:42 |
| S59 | 6 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1) with (root near1 mean near1 square) and (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 12:27 |
| S60 | 5 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1) with (root near1 mean near1 square) same (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 12:43 |

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| S61 | 207 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1 or uneven or surface) same (root near1 mean near1 square) same (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 12:47 |
| S62 | 19 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1) same (root near1 mean near1 square) same (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 14:08 |
| S63 | 24 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1 or uneven or pore\$1 or porous) same (root near1 mean near1 square) same (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 12:48 |
| S64 | 2 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1) same (root near1 mean near1 square) same (angstrom\$1 or nanometer\$1 or nm) and depth same (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 14:09 |
| S65 | 12 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1) same (root near1 mean near1 square) same (angstrom\$1 or nanometer\$1 or nm) and (depth or deep or thick or thickness) same (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 14:22 |
| S66 | 12 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1) same (root near1 mean near1 square) same (angstrom\$1 or nanometer\$1 or nm) and (depth or deep or thick or thickness or holes or hole) same (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 14:30 |

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| S67 | 13 | ion with etch\$3 and (pit\$4 or hole\$1 or cavity or cavities or path\$1 or channel\$1) same (root near1 mean near1 square) same (angstrom\$1 or nanometer\$1 or nm) and (pitting or pitted or pits or pit or depth or deep or thick or thickness or holes or hole) same (angstrom\$1 or nanometer\$1 or nm) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 14:32 |
| S68 | 1 | S67 not S66 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/01/31 14:32 |
| S69 | 1 | ink\$jet\$4 with silicon and di\$electric and micro\$fluid | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/31 15:12 |
| S70 | 23 | ink\$jet\$4 with silicon and (path\$1 or channel\$1) and micro\$fluid\$2 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/01/31 15:13 |
| S71 | 2 | "6183067".pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/02/01 13:30 |
| S72 | 1495 | 347/56 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/02/01 13:30 |
| S74 | 5 | "6402308" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/02/01 13:58 |

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| S75 | 23 | CHEN.in. and WU.in. and LUR.in. and silicon and etch\$3 and oxide | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:18 |
| S76 | 1922 | ((deep near reactive near ion near etch\$3) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:18 |
| S77 | 116 | ((deep near reactive near ion near etch\$3) and "347"/\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:19 |
| S78 | 44 | ((deep near reactive near ion near etch\$3) with silicon) and "347"/\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:20 |
| S79 | 9 | ((deep near reactive near ion near etch\$3) with silicon) and Angstrom\$1 and "347"/\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:20 |
| S80 | 37 | ((deep near reactive near ion near etch\$3) with silicon) and "347"/\$3 not silverbrook.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 11:12 |
| S81 | 36105 | ((deep near reactive near ion near etch\$3) with silicon) and (dielectric or (free near pitted) or (mean near square near depth)) "347"/\$3 not silverbrook.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:34 |
| S82 | 8 | ((deep near reactive near ion near etch\$3) with silicon) and (dielectric or (free near pitted) or (mean near square near depth)) and "347"/\$3 not silverbrook.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:34 |

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| S83 | 9 | ((deep near reactive near ion near etch\$3) with silicon) and (di\$electric or (free near pitted) or (root near4 depth)) and "347"/\$3 not silverbrook.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:35 |
| S84 | 9 | ((deep near reactive near ion near etch\$3) with silicon) and (di\$electric or (free near pit\$4) or (root near4 depth)) and "347"/\$3 not silverbrook.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:42 |
| S85 | 115 | ((((deep near reactive near ion near etch\$3) or (dry near etch\$3)) with silicon) and (di\$electric or (free near pit\$4) or (root near4 depth)) and "347"/\$3 not silverbrook.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 09:46 |
| S86 | 9 | ((((deep near reactive near ion near etch\$3) or (dry near etch\$3)) with silicon) and (angstrom with (di\$electric or (free near pit\$4) or (root near4 depth))) and "347"/\$3 not silverbrook.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 10:10 |
| S87 | 1 | "5861902".pn. and etch and silicon and dielectric | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 10:11 |
| S88 | 1 | "5861902".pn. and etch\$3 and silicon and dielectric | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 11:17 |
| S89 | 18 | ((deep near reactive near ion near etch\$3) with (dry near etch\$3) with silicon) and "347"/\$3 not silverbrook.in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/06/09 11:14 |
| S90 | 0 | "5861902".pn. and angstorom | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 11:17 |

EAST Search History

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| S91 | 1 | "5861902".pn. and angstrom | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 12:05 |
| S92 | 2 | (root near mean near square near depth) and ((deep near reactive near ion near etch\$3) or (dry near etch\$3)) and (ink or ink\$jet\$4 or jet\$4) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 12:15 |
| S93 | 2 | (root near mean near square near depth) and ((etch\$3)) and (ink or ink\$jet\$4 or jet\$4) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 12:14 |
| S94 | 3 | (root near mean near square near depth) and ((etch\$3)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 12:14 |
| S95 | 3 | (root near mean near square near depth) and ((deep near reactive near ion near etch\$3) or (dry near etch\$3)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 12:19 |
| S96 | 2 | "5861902".pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 12:19 |
| S97 | 4 | ("5861902" or "5143577").pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 12:19 |
| S98 | 1 | ("5861902" or "5143577").pn. and square with mean with root | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/06/09 12:19 |

EAST Search History

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| S99 | 1 | 10/823939 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/06/19 09:32 |
| S10 0 | 2 | "20020113840" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/06/19 09:43 |
| S10 1 | 2 | "20020113846" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/06/19 09:43 |
| S10 2 | 2 | "5861902".pn. and dielectric | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/06/19 09:53 |
| S10 3 | 1 | "5861902".pn. and dielectric and (angstrom) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | ON | 2006/06/19 09:53 |
| S10 4 | 1 | "5861902".pn. and dielectric same (angstrom) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | ON | 2006/06/19 09:54 |
| S10 5 | 56 | "347"/\$3 and (dielectric with angstrom) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | ON | 2006/06/19 09:55 |
| S10 6 | 19 | "347"/\$3 and (dielectric with angstrom) same etch\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | ON | 2006/06/19 09:55 |

EAST Search History

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| S107 | 2 | "20020113846" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/07/06 12:03 |
| S108 | 2 | "5861902".pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/07/06 12:03 |
| S109 | 483 | "347"/\$3 and (etch\$3) and angstrom | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | ON | 2006/07/06 12:44 |
| S110 | 48 | "347"/\$3 and (etch\$3) and (angstrom with (di\$electric)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | ON | 2006/07/06 13:07 |
| S111 | 3 | "347"/\$3 and (before with etch\$3) same (angstrom with (di\$electric)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | ON | 2006/07/06 13:07 |
| S112 | 3 | "347"/\$3 and ((before or prior) with etch\$3) same (angstrom with (di\$electric)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | ON | 2006/07/06 13:19 |
| S113 | 7795 | "347"/\$3 and (etch\$3) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/10/31 15:12 |
| S114 | 1579 | "347"/\$3 and (etch\$3) and (Angstrom or A) same (di\$electric) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/10/31 15:12 |

EAST Search History

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| S11 5 | 1389 | "347"/\$3 and (etch\$3) and (Angstrom or A) same (di\$1electric) and silicon | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/10/31 15:13 |
| S11 6 | 464 | "347"/\$3 and (etch\$3) and (Angstrom or A) same (di\$1electric) and silicon and (pitted or pitting or pits or pit) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/10/31 15:17 |
| S11 7 | 1 | 10/823939 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/10/31 15:18 |
| S11 8 | 18 | "5861902" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/11/01 09:58 |
| S11 9 | 8 | "5861902" not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/11/01 09:59 |
| S12 0 | 2 | "5861902".pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 10:40 |
| S12 1 | 35840533 | "5861902".pn. and Angstrom\$1 or A | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 10:40 |
| S12 2 | 1 | "5861902".pn. and Angstrom\$1 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 10:47 |

EAST Search History

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| S12 3 | 2 | "5143577".pn. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 10:48 |
| S12 4 | 1269487 | "5143577".pn. and print\$3 or jet\$3 or eject\$3 or ink | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 10:48 |
| S12 5 | 1 | "5143577".pn. and (print\$3 or jet\$3 or eject\$3 or ink) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 10:52 |
| S12 6 | 0 | "347"/\$3 and ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted) with Angstrom) and ((root near mean near square) or (square near root with average)) same (depth same (pitting or pit\$1 or pitted or crater\$1)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 11:00 |
| S12 7 | 0 | "347"/\$3 and ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted) same Angstrom) and ((root near mean near square) or (square near root with average)) same (depth same (pitting or pit\$1 or pitted or crater\$1)) same angstrom | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 11:03 |
| S12 8 | 1 | ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted) same Angstrom) and ((root near mean near square) or (square near root with average)) same (depth same (pitting or pit\$1 or pitted or crater\$1)) same angstrom | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 11:05 |
| S12 9 | 1 | ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted) same Angstrom) and ((root with mean with square) or (square with root with average) or (square with root)) same (depth same (pitting or pit\$1 or pitted or crater\$1)) same angstrom | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 11:05 |

EAST Search History

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| S13 0 | 4 | ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted) same (a or Angstrom)) and ((root with mean with square) or (square with root with average) or (square with root)) same (depth same (pitting or pit\$1 or pitted or crater\$1)) same (angstrom or A) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 12:05 |
| S13 1 | 24 | ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted)) and ((root with mean with square) or (square with root with average) or (square with root)) same (depth same (pitting or pit\$1 or pitted or crater\$1)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 12:06 |
| S13 2 | 2 | ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted)) and ((root with mean with square) or (square with root with average) or (square with root)) same (depth same (pitting or pit\$1 or pitted or crater\$1)) and "347"/\$4 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 12:32 |
| S13 3 | 6 | ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted)) and ((root with mean with square) or (square with root with average) or (square with root)) same (depth same (pitting or pit\$1 or pitted or crater\$1)) and (ink\$jet\$4 or print\$3) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 12:30 |
| S13 4 | 5 | ((crater\$1 or smooth or smoothness or (surface near pit\$4) or pitting or pits or pitted)) and ((root with mean with square) or (square with root with average) or (square with root)) same (depth same (pitting or pit\$1 or pitted or crater\$1 or surface)) and "347"/\$4 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/03 12:32 |
| S13 5 | 2055 | (surface with (pit\$4 or rough\$4)) same (root with (mean or average) with square) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/11/08 15:18 |
| S13 6 | 10 | (surface with (pit\$4 or rough\$4)) same (root with (mean or average) with square) and "347"/\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/11/08 15:26 |

EAST Search History

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|----------|---------|---------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------|-----|-----|------------------|
| S13 7 | 1 | (surface with (pit\$4 or rough\$4)) same dielectric same (root with (mean or average) with square) and "347"/\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/11/08 15:21 |
| S13 8 | 3 | dielectric same (root with (mean or average) with square) and "347"/\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/11/08 15:21 |
| S13 9 | 1539589 | "20020113846" ion | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/11/08 15:26 |
| S14 0 | 1 | "20020113846" ion | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | AND | OFF | 2006/11/08 15:27 |
| S14 1 | 71696 | (a or angstrom) with (dielectric near layer\$3) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:29 |
| S14 2 | 574 | (a or angstrom) with (dielectric near layer\$3) and "347"/\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:29 |
| S14 3 | 405 | (a or angstrom) near4 (dielectric near layer\$3) and "347"/\$3 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:30 |
| S14 4 | 218 | (a or angstrom) near4 (dielectric near layer\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:32 |

EAST Search History

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| S14 5 | 6 | (angstrom) near4 (dielectric near layer\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:33 |
| S14 6 | 1 | (angstrom) near4 (dielectric) with (before near etch\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:34 |
| S14 7 | 1 | (angstrom or A) near4 (dielectric) with (before near etch\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:34 |
| S14 8 | 4 | (angstrom or A) near4 (dielectric or bielectric or layer) with (before near etch\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:34 |
| S14 9 | 4 | (angstrom or A) near4 (dielectric or bielectric or layer\$3) with (before near etch\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:36 |
| S15 0 | 8 | (angstrom or A) near4 (dielectric or bielectric or layer\$3) with ((before or prior) near etch\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:38 |
| S15 1 | 294 | (angstrom or A) near4 (dielectric or bielectric or layer\$3) with (etch\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:37 |
| S15 2 | 23 | (angstrom) near4 (dielectric or bielectric or layer\$3) with (etch\$3) and "347"/\$3 not silverbrook | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 12:46 |

EAST Search History

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| S15 3 | 154 | "347"/\$3 and ((dielectric or insulat\$3 or non\$1conduct\$3) with (surface or material or element or thickness) with Angstrom) or ((dielectric or insulat\$3 or non\$1conduct\$3) with angstrom with ((root near mean) or (root near average) or (square with mean) or (square with average))) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 13:06 |
| S15 4 | 29 | "347"/\$3 and ((dielectric or insulat\$3 or non\$1conduct\$3) with (surface or material or element or thickness) with (etch\$3 or engrav\$3) with Angstrom) or ((dielectric or insulat\$3 or non\$1conduct\$3) with angstrom with ((root near mean) or (root near average) or (square with mean) or (square with average))) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 13:11 |
| S15 5 | 1 | "347"/\$3 and ((dielectric or insulat\$3 or non\$1conduct\$3) with angstrom with ((root near mean) or (root near average) or (square with mean) or (square with average)). and (pit\$4 or hole or surface) with depth) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 13:16 |
| S15 6 | 1 | "347"/\$3 and ((dielectric or insulat\$3 or non\$1conduct\$3) with angstrom with ((root near mean) or (root near average) or (square with mean) or (square with average)) and (pit\$4 or hole or surface)) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2007/02/13 13:16 |